

Docket No.: 249945US2



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

IN RE APPLICATION: Takahiro INOUE

SERIAL NO.: 10/791,825

GAU: 2816

FILED: March 4, 2004

EXAMINER: NGUYEN, LONG T.

FOR: SEMICONDUCTOR APPARATUS

LETTER SUBMITTING REPLACEMENT DRAWING SHEET(S)

COMMISSIONER FOR PATENTS
Alexandria, VA 22313

SIR:

Responsive to the below indicated communication, the following drawing sheets are submitted herewith:

☒ 2 Replacement Drawing Sheets

☐ _____ New Drawing Sheets

☒ Official Action dated December 23, 2005.

☐ Notice of Allowance/Issue Fee dated _____

☐ Other dated _____

The changes and/or modifications made include the following:

Adding the ground to the node with the emitter of the MOS-type device (Figures 1 and 3), and connecting the floating terminal of the switch SWoff1 with the node of the emitter of the MOS device (Figure 1).

Respectfully Submitted,

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